| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-----------|--------|---|---|---------------------|---------|------------------|
| <u>11</u> | 158 | group-III near nitride near2 semiconductor | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/04/03 14:43 |
| L2 | 106294 | (boron near phosphide) or BP | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/04/03 14:44 |
| L3 | 25 | I1 and I2 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/04/03 14:44 |